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- Each Device Drives 12 Lines
- 60-V Output Voltage Swing Capability
- 25-mA Output Source Current Capability
- High-Speed Serially-Shifted Data Input
- TTL-Compatible Inputs
- Latches on All Driver Outputs

description

The SN65512B and SN75512B are monolithic BIDFET[†] integrated circuits designed to drive a dot matrix or segmented vacuum fluorescent display.

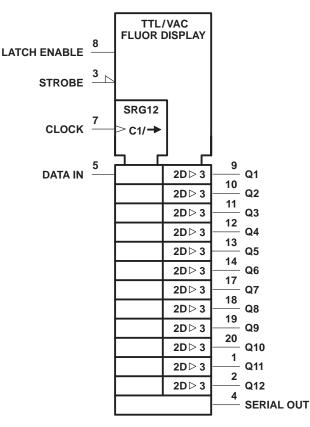
All device inputs are diode-clamped pnp inputs and assume a high logic level when open circuited. The nominal input threshold voltage is 1.5 V. Outputs are totem-pole structures formed by an npn emitter-follower and double-diffused MOS (DMOS) transistors.

The device consists of a 12-bit shift register, 12 latches, and 12 output AND gates. Serial data is entered into the shift register on the low-to-high transition of CLOCK. When high, LATCH ENABLE transfers the shift register contents to the outputs of the 12 latches. The active-low STROBE input enables all Q outputs. Serial data output from the shift register can be used to cascade shift registers. This output is not affected by LATCH ENABLE or STROBE.

The SN65512B is characterized for operation from -40° C to 85° C. The SN75512B is characterized for operation from 0° C to 70° C.

DW	DW OR N PACKAGE (TOP VIEW)						
Q11 [1	20] Q10				
Q12 [2	19] Q9				
STROBE]	3	18] Q8				
SERIAL OUT [4	17] Q7				
DATA IN [5	16] V _{CC2}				
V _{CC1} [6	15] GND				
CLOCK [7	14] Q6				
LATCH ENABLE [8	13] Q5				
Q1 [9	12] Q4				
Q2]	10	11] Q3				

logic symbol[‡]



[‡] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

†BIDFET – Bipolar, double-diffused, N-channel and P-channel MOS transistors on same chip. This is a patented process.

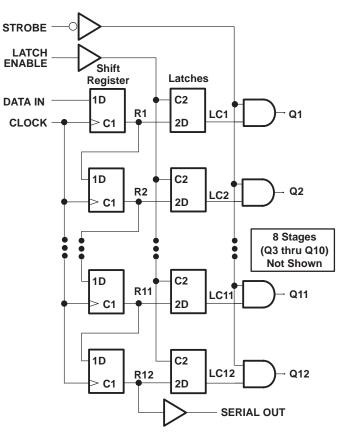
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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logic diagram (positive logic)



FUNCTION TABLE

	CONTROL INP		UTS				OUTPUTS
FUNCTION	CLOCK	LATCH ENABLE	STROBE	SHIFT REGISTER R1 THRU R12	LATCHES LC1 THRU LC12	SERIAL	Q1 THRU Q12
Load	↑ No ↑	Х	Х	Load and shift [†] No change	Determined by LATCH ENABLE [‡]	R12	Determined by STROBE
Latch	х	L H	х	As determined above	Stored data New data	R12	Determined by STROBE
Strobe	х	х	H L	As determined above	Determined by LATCH ENABLE [‡]	R12	All LC LC1 thru LC12, respectively

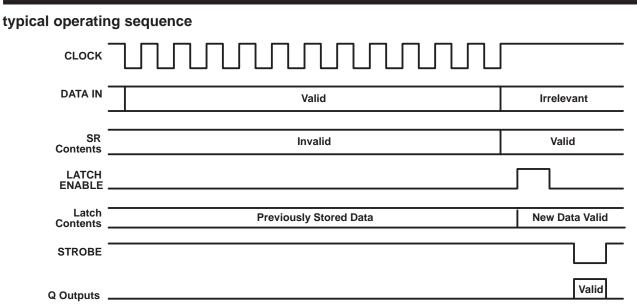
H = high level, L = low level, X = irrelevant, \uparrow = low-to-high-level transition

[†]R12 takes on the state of R11, R11 takes on the state of R10, ... R2 takes on the state of R1, and R1 takes on the state of the data input.

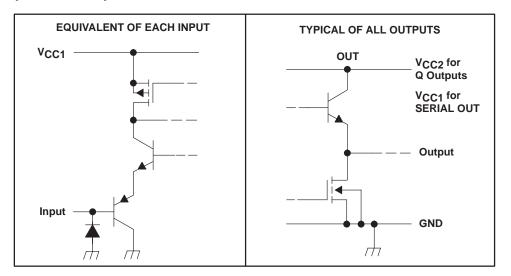
[‡]New data enter the latches while LATCH ENABLE is high. These data are stored while LATCH ENABLE is low.



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schematics of inputs and outputs





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC2}		
Continuous total power dissipation	SN65512B	See Dissipation Rating Table 40°C to 85°C
Storage temperature range, T _{stg} Lead temperature 1,6 mm (1/16 inch) from		-65°C to 150°C 260°C

NOTES: 1. Voltage values are with respect to network ground terminal.

_	DISSIPATION RATING TABLE						
	PACKAGE	$T_A \le 25^{\circ}C$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING		
Γ	DW	1125 mW	9.0 mW/°C	720 mW	585 mW		
	Ν	1150 mW	9.2 mW/°C	736 mW	589 mW		

recommended operating conditions

			SN65512B		SN75512B		
			MIN	MAX	MIN	MAX	UNIT
Supply voltage, V _{CC1}			5	15	5	15	V
Supply voltage, V _{CC2}			0	60	0	60	V
High-level input voltage, VIH			2		2		V
Low-level input voltage, VIL				0.8		0.8	V
High-level output current, I _{OH}				-25		-25	mA
Low-level output current, IOL	V _{CC1} = 10 V			5		5	mA
	V _{CC1} = 15 V,	T _A = 25°C	0	4	0	4	MHz
Clock frequency, fclock	V _{CC1} = 5 V,	T _A = 25°C	0	1	0	1	
Dulas duration OLOOK bish on low t	V _{CC1} = 15 V,	T _A = 25°C	100		100		ns
Pulse duration, CLOCK high or low, t _W	V _{CC1} = 5 V,	T _A = 25°C	500		500		
Satura tima DATA IN valid batara CLOCK \uparrow to (and Figure 1)	V _{CC1} = 15 V,	T _A = 25°C	100		100		
Setup time, DATA IN valid before CLOCK \uparrow, t_{SU} (see Figure 1)	V _{CC1} = 5 V,	T _A = 25°C	250		250		ns
Hold time DATA IN volid offer $CLOCK^{\uparrow}$ to (see Figure 1)	V _{CC1} = 15 V,	T _A = 25°C	50		50		
Hold time, DATA IN valid after CLOCK \uparrow , t _h (see Figure 1) V _{CC} .		T _A = 25°C	250		250		ns
Operating free-air temperature, T _A			-40	85	0	70	°C



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electrical characteristics over recommended operating free-air temperature range, $V_{CC2} = 60 V$ (unless otherwise noted)

	PARAME	TER	TEST CO	NDITIONS	MIN	TYP†	MAX	UNIT	
VIК	Input clamp voltage		lj = – 12 mA				-1.5	V	
		Q outputs	$I_{OH} = -25 \text{ mA},$	V _{CC1} = 10 V	57.5	58			
VOH	High-level output voltage	SERIAL OUT	$I_{OH} = -200 \ \mu A$,	V _{CC1} = 10 V	9	9.5		V	
		Q outputs	$I_{OL} = 5 \text{ mA},$	V _{CC1} = 10 V		2.6	5	N/	
VOL Low-level output voltage	Low-level output voltage	SERIAL OUT	$I_{OL} = 200 \ \mu A$,	V _{CC1} = 10 V		0.05	0.2	V	
Ιн	High-level input current		V _{CC1} = 15 V,	V _I = 5 V		0.01	1	μΑ	
١ _{IL}	Low-level input current		V _{CC1} = 15 V,	V _I = 0.8 V		-25	-150	μΑ	
			V _I = 5 V		80	500	μΑ		
ICC1 Supply current from VCC1			V _{CC1} = 15 V	V _I = 0.8 V		2	6	mA	
la a Cumplu sumanté	Supply ourrent from Voco			All outputs high		10	100	μΑ	
ICC2	Supply current from V _{CC2}		V _{CC1} = 15 V	STROBE at 2 V		0.8	3	mA	

[†] All typical values are at $V_{CC1} = 5 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C}.$

switching characteristics, V_{CC1} = 10 V, V_{CC2} = 60 V, T_A = 25°C

	PARAMETER	TEST CON	MIN	MAX	UNIT	
^t PHL	Propagation delay time, high-to-low level output				300	ns
t _{PLH}	Propagation delay time, low-to-high level output	C _I = 30 pF, See Figure 2			300	ns
^t THL	tTHL Transition time, high-to-low level output		See Figure 2		500	ns
^t TLH	Transition time, low-to-high level output	1			500	ns



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PARAMETER MEASUREMENT INFORMATION

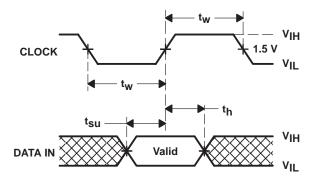


Figure 1. Input Timing Voltage Waveforms

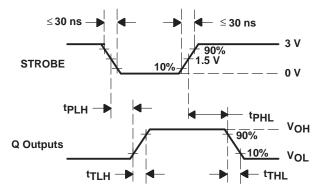


Figure 2. Switching Time Voltage Waveforms



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